



Bipolar PNP Bare Die – BTP993

Part Description

The BTP993 is a silicon BJT transistor available in bare die form and well suited for use in High Speed Switching applications.

Key Parameters:

- VCBO = -40V
- VCEO = -40V
- VEBO = -6V
- hFE = 100-300 @ VCE = -1V, IC = -0.01A
- VCE(Sat) = -0.4V @ IC = -0.05A, IB = -5mA
- fT = 250 MHz @ VCE = -20V, IE = 0A
- COBO = 4pF @ VCB = -5V

Features

Designed to provide performance equivalent to FAIRCHILD / ON SEMI MMBT3906, 2N3906

Die Size (Unawn)

280µm X 280µm, 11 Mils X 11 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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